

**PAGE SPECIAL ISSUE: 2008 U.S. WORKSHOP ON THE PHYSICS AND CHEMISTRY OF II-VI MATERIALS**

- 1521 Foreword  
*S. Sivananthan, Y. Anter, and N.K. Dhar*
- 1522 AFM Characterization of Raman Laser-Induced Damage on CdZnTe Crystal Surfaces  
*Lucile C. Teague, Samantha A. Hawkins, Martine C. Duff, Michael Groza, Vladimir Buliga, and Arnold Burger*
- 1528 A Scanning Probe Microscopy Study of Cd<sub>1-x</sub>Zn<sub>x</sub>Te  
*C.K. Egan, P. Dabrowski, Z. Klusek, and A.W. Brinkman*
- 1533 Characterization of CdTe and HgCdTe by Photo-Thermal Excitation Spectroscopy  
*Robert Furstenberg, Michael R. Papantonakis, and C.A. Kendziora*
- 1539 *Ab Initio* Studies of Hydrogen Defects in CdTe  
*Zs. Rak, S.D. Mahanti, and Krishna C. Mandal*
- 1548 Growth of Thick Epitaxial CdTe Films by Close Space Sublimation  
*Q. Jiang, A.W. Brinkman, B.J. Cantwell, J.T. Mullins, Fabrice Dierre, A. Basu, P. Veeramani, and P. Sellin*
- 1554 Magneto-optical Studies of Spin Phenomena in CdMnTe Doped with Co and Cr  
*S. Shen, X. Liu, K. Tivakornsasithorn, Y.H. Cho, J.K. Furdyna, M. Dobrowolska, Y.H. Hwang, and Y.H. Um*
- 1558 Structural Characterization of Integrated II-VI and III-V Heterostructures for Solar Cell Applications  
*X. Zhang, S. Wang, D. Ding, X. Liu, J.-H. Tan, J.K. Furdyna, Y.-H. Zhang, and D.J. Smith*
- 1563 Internal Electric Field Investigations of a Cadmium Zinc Telluride Detector Using Synchrotron X-ray Mapping and Poekels Effect Measurements  
*G. Yang, A.E. Bolotnikov, G.S. Camarda, Y. Cui, A. Hossain, H.W. Yao, and R.B. James*
- 1568 Effects of Annealing in a Partially Reducing Atmosphere on Sputtered Al-Doped ZnO Thin Films  
*C. Lennon, R.B. Tapia, R. Kodama, Y. Chang, S. Sivananthan, and M. Deshpande*
- 1574 Novel Quantum Dot Gate FETs and Nonvolatile Memories Using Lattice-Matched II-VI Gate Insulators  
*F.C. Jain, E. Suarez, M. Gogna, F. Alamoody, D. Butkiewicz, R. Hohner, T. Liaskas, S. Karmakar, P.-Y. Chan, B. Miller, J. Chandy, and E. Heller*
- 1579 Performance and Modeling of the MWIR HgCdTe Electron Avalanche Photodiode  
*Jeffrey Beck, Richard Scritchfield, Billy Sullivan, Jamie Teherani, Chang-Feng Wan, Mike Kinch, Martha Ohlson, Mark Shokan, Lewis Wood, Pradip Mitra, Mike Goodwin, and Jim Robinson*
- 1593 Vanadium-Doped Cadmium Manganese Telluride (Cd<sub>1-x</sub>Mn<sub>x</sub>Te) Crystals as X- and Gamma-Ray Detectors  
*A. Hossain, Y. Cui, A.E. Bolotnikov, G.S. Camarda, G. Yang, D. Kochanowska, M. Witkowska-Baran, A. Mycielski, and R.B. James*
- 1600 Growth of CdTe Films on Amorphous Substrates Using CaF<sub>2</sub> Nanorods as a Buffer Layer  
*Nicholas Licausi, Wen Yuan, Fu Tang, Thomas Parker, Huafang Li, Gwo-Ching Wang, Toh-Ming Lu, and Ishwara Bhat*
- 1605 Multifunctional ZnO-Based Thin-Film Bulk Acoustic Resonator for Biosensors  
*Ying Chen, Pavel I. Reyes, Ziqing Duan, Gaurav Saraf, Richard Wittstruck, Yicheng Lu, Olena Taratula, and Elena Galoppini*
- 1612 Dye-Sensitized Solar Cells Combining ZnO Nanotip Arrays and Nonliquid Gel Electrolytes  
*Hanhong Chen, Ziqing Duan, Yicheng Lu, and Aurelien Du Pasquier*
- 1618 Metalorganic Vapor-Phase Epitaxial Growth of (211)B CdTe on (211) Si Using Ge Interfacial Layer  
*S.R. Rao, S.S. Shintri, and I.B. Bhat*

- 1624 Spectral Response Model for Front-Side-Illuminated Detectors  
*E. Robinson, A.I. D'Souza, M.G. Stapelbroek, M.R. Skokan, M.A. Kinch, H.D. Shih, and Priyala S. Wijewarnasuriya*
- 1628 Experimental Performance and Monte Carlo Modeling of Long Wavelength Infrared Mercury Cadmium Telluride Avalanche Photodiodes  
*S. Derelle, S. Bernhardt, R. Haidar, J. Deschamps, J. Primot, J. Rothman, S. Rommeluere, and N. Guérineau*
- 1637 Chemical-Mechanical Polishing of CdTe and  $Zn_xCd_{1-x}$ Te Single Crystals by  $H_2O_2/HNO_3/HBr$ -Organic Solvent Etchant Compositions  
*Z.F. Tomashik, V.M. Tomashik, I.B. Stratiychuk, G.M. Okrepka, I.I. Hnativ, P. Moravec, P. Höschl, and J. Bok*
- 1645 Chemical Interaction of CdTe and CdZnTe with Aqueous Solutions of  $H_2O_2$ -HI-Tartaric Acid  
*P. Moravec, V.G. Ivanits'ka, J. Franc, Z.F. Tomashik, V.M. Tomashik, K. Mašek, P.I. Feychuk, L.P. Shcherbak, P. Höschl, R. Grill, and J. Walter*
- 1652 *In Situ* Spectroscopic Ellipsometry of Rough Surfaces: Application to CdTe(211)B/Ge(211) Grown by Molecular-Beam Epitaxy  
*Giacomo Badano, Xavier Baudry, and Ivan C. Robin*
- 1661 Influence of Oxygen Post-Growth Annealing on Optical and Electrical Properties of PbSe Thin Films  
*Fanghai Zhao, Jiangang Ma, Donghui Li, Shaibal Mukherjee, Gang Bi, and Zhisheng Shi*
- 1666 Generation-Recombination Effect in High-Temperature HgCdTe Heterostructure Nonequilibrium Photodiodes  
*K. Jóźwikowski, J. Piotrowski, W. Gawron, A. Rogalski, A. Piotrowski, J. Pawluczyk, A. Jóźwikowska, J. Ruthowski, and M. Kopytko*
- 1677 Experimental Electron Mobility in ZnO: A Reassessment Through Monte Carlo Simulation  
*Francesco Bertazzi, Enrico Bellotti, Enrico Furno, and Michele Goano*
- 1684 HgCdTe *p-on-n* Focal-Plane Array Fabrication Using Arsenic Incorporation During MBE Growth  
*O. Gravrand, Ph. Ballet, J. Baylet, and N. Baier*
- 1690 Critical Thickness of Exponentially and Linearly Graded HgCdTe/CdZnTe  
*C. Fulk, T. Parodos, P. Lamarre, S. Tobin, P. LoVecchio, and J. Markunas*
- 1698 A Novel Stress Characterization Technique for the Development of Low-Stress Ohmic Contacts to HgCdTe  
*D. D'Orsogna, P. Lamarre, E. Bellotti, P.E. Barbone, F. Smith, C. Fulk, P. LoVecchio, M.B. Reine, S.P. Tobin, and J. Markunas*
- 1707 High-Operating-Temperature HgCdTe Avalanche Photodiodes  
*J. Rothman, N. Baier, P. Ballet, L. Mollard, M. Fournier, J.S. Gout, and J.-P. Chamonal*
- 1717 Empirical Pseudopotential and Full-Brillouin-Zone  $k \cdot p$  Electronic Structure of CdTe, HgTe, and  $Hg_{1-x}Cd_x$ Te  
*Michele Penna, Alberto Marnetto, Francesco Bertazzi, Enrico Bellotti, and Michele Goano*
- 1726 Extended X-ray Absorption Fine Structure Investigation of Arsenic in HgCdTe: the Effect of the Activation Anneal  
*P. Ballet, B. Polge, X. Biquard, and I. Alliot*
- 1733 Study of LWIR and VLWIR Focal Plane Array Developments: Comparison Between *p-on-n* and Different *n-on-p* Technologies on LPE HgCdTe  
*O. Gravrand, L. Mollard, C. LARGERON, N. Baier, E. Deborniol, and Ph. Chorier*
- 1741 Plasma Passivation Etching for HgCdTe  
*A.J. Stoltz, J.D. Benson, and P.J. Smith*
- 1746 Characterization of Dislocations in HgCdTe Heteroepitaxial Layers Using a New Substrate Removal Technique  
*P. Lamarre, C. Fulk, D. D'Orsogna, E. Bellotti, F. Smith, P. LoVecchio, M.B. Reine, T. Parodos, J. Marciniak, S.P. Tobin, and J. Markunas*
- 1755 Flexibility of *p-n* Junction Formation from SWIR to LWIR Using MBE-Grown  $Hg_{(1-x)}Cd_x$ Te on Si Substrates  
*M.F. Vilela, S.F. Harris, R.E. Kvaas, A.A. Buell, M.D. Newton, K.R. Olsson, D.D. Lofgreen, and S.M. Johnson*
- 1764 Progress in the Molecular Beam Epitaxy of HgCdTe on Large-Area Si and CdZnTe Substrates  
*M. Reddy, J.M. Peterson, S.M. Johnson, T. Vang, J.A. Franklin, E.A. Patten, W.A. Radford, J.W. Bangs, and D.D. Lofgreen*
- 1771 Topography and Dislocations in (112)B HgCdTe/CdTe/Si  
*J.D. Benson, P.J. Smith, R.N. Jacobs, J.K. Markunas, M. Jaime-Vasquez, L.A. Almeida, A. Stoltz, L.O. Bubulac, M. Groenert, P.S. Wijewarnasuriya, G. Brill, Y. Chen, and U. Lee*
- 1776 Microstructure of Heteroepitaxial ZnTe Grown on GaAs(211)B by Molecular Beam Epitaxy  
*X.J. Wang, Y.B. Hou, Y. Chang, C.R. Becker, R.F. Klie, and S. Sivananthan*
- 1781 The Effect of Wet Etching on Surface Properties of HgCdTe  
*R. Sporken, R. Kiran, T. Casselman, F. Agariden, S. Velicu, Yong Chang, and S. Sivananthan*

- 1790 Study of the Transit-Time Limitations of the Impulse Response in Mid-Wave Infrared HgCdTe Avalanche Photodiodes  
*Gwladys Perrais, Sophie Derelle, Laurent Mollard, Jean-Paul Chamonal, Gerard Destefanis, Gilbert Vincent, Sylvie Bernhardt, and Johan Rothman*
- 1800 Strained and Unstrained Layer Superlattices for Infrared Detection  
*C.H. Grein, J. Garland, and M.E. Flatté*
- 1805 Planar p-on-n HgCdTe FPAs by Arsenic Ion Implantation  
*L. Mollard, G. Destefanis, N. Baier, J. Rothman, P. Ballet, J.P. Zanatta, M. Tchagaspian, A.M. Papon, G. Bourgeois, J.P. Barnes, C. Pautet, and P. Fougères*

